

## **ISC Silicon NPN Power Transistor**

# 2SD1575

### **DESCRIPTION**

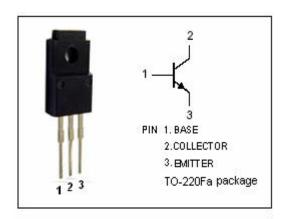
- · High Breakdown Voltage-
  - : V<sub>CBO</sub>= 1200V (Min)
- · High Switching Speed
- High Reliability
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

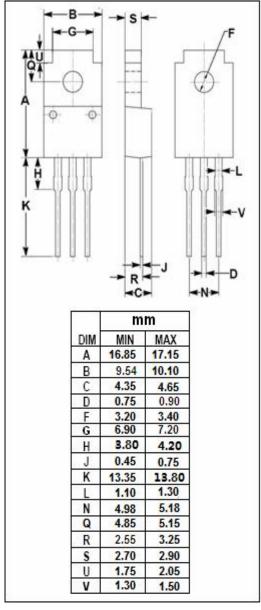
### **APPLICATIONS**

· Designed for horizontal deflection output applications

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	1200	V	
V <sub>CES</sub>	Collector-Emitter Voltage	1200	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	700	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
Ic	Collector Current- Continuous	2	Α	
Іср	Collector Current-Peak	6	Α	
I <sub>BP</sub>	Base Current-Peak	2.5	Α	
Івр	Reverse Base Current-Peak	1.5	Α	
Pc	Collector Power Dissipation @ $T_C$ =25 $^{\circ}$ C	40	W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	







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### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

16-25 C uniess otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA ; I <sub>C</sub> = 0	6			V			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 1A			5.0	V			
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 1A			1.5	V			
І <sub>СВО</sub>	Collector Cutoff Current	V <sub>CB</sub> = 750V ; I <sub>E</sub> = 0			50	μА			
		V <sub>CB</sub> = 1200V ; I <sub>E</sub> = 0			1.0	mA			
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V ; I <sub>C</sub> = 0			50	μА			
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 2A; V <sub>CE</sub> = 5V	2						
Switching times									
tstg	Storage Time				9	μ <b>S</b>			
t <sub>f</sub>	Fall Time	$I_C$ = 2.5A; $I_{B1(end)}$ = 1.1A; $L_B$ = 10 $\mu$ H			1.0	μS			

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